

# AP7217D

#### 1.2V 600mA CMOS LDO

#### **Features**

- Low Current Consumption: Typ. 40µA
- Output Voltage: 1.2V
- Guaranteed 600mA Output Current
- Dropout Voltage 850mV at 600mA Output Current
- Input Voltage Range: 2.5V to 5.5V
- Current Limit Protection
- Thermal shutdown Protection
- Stability with Low ESR Capacitors
- Low Temperature Coefficient
- SOT89-3L: Available in "Green" Molding Compound (No Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

### **General Description**

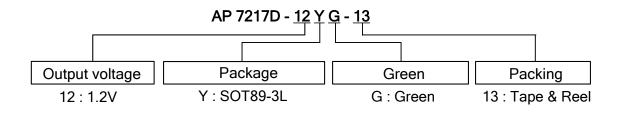
The AP7217D low-dropout linear regulator operates from 2.5V to 5.5V supply and delivers a guaranteed 600mA continuous load current.

The space-saving SOT89-3L package is suitable for "pocket" and hand-held application.

### Applications

- CD and MP3 Players
- Cellular and PCS Phones
- Digital Still Camera
- Hand-Held Computers

## **Ordering Information**



Device	Package	Packaging	13" Tape and Reel		
Device	Code	(Note 2)	Quantity	Part Number Suffix	
🐏 AP7217D-12YG-13	Y	SOT89-3L	2500/Tape & Reel	-13	

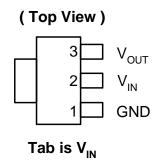
Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at

<u>http://www.diodes.com/products/lead\_free.html</u>.
Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <a href="http://www.diodes.com/datasheets/ap02001.pdf">http://www.diodes.com/datasheets/ap02001.pdf</a>.



#### **Pin Assignments**

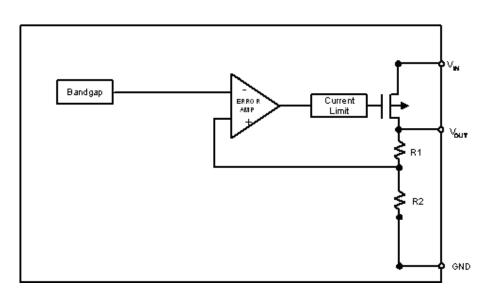
(1) SOT89-3L



# **Pin Descriptions**

Pin Name	Pin No.	Function
GND	1	Ground
V <sub>IN</sub>	2	Supply Voltage
V <sub>OUT</sub>	3	Voltage Output

# **Block Diagram**



AP7217D Rev. 2
----------------

2 of 9 www.diodes.com



### **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit	
ESD HBM	Human Body Model ESD Protection	3	KV	
ESD MM	Machine Model ESD Protection	450	V	
V <sub>IN</sub>	Input Voltage	+6	V	
P <sub>D</sub>	Power Dissipation @ TA=25 °C (Note 3)	SOT89-3L	578	mW
T <sub>MJ</sub>	Maximum Junction Temperature	150	°C	

Notes: 3. Maximum P<sub>D</sub> is under minimum recommended pad layout condition.

# **Recommended Operating Conditions**

Symbol	Parameter	Min	Мах	Unit
V <sub>IN</sub>	Input Voltage	2.5	5.5	V
I <sub>OUT</sub>	Output Current	0	600	mA
T <sub>A</sub>	Operating Ambient Temperature	-40	85	°C
TJ	Operating Junction Temperature	-40	125	٥C



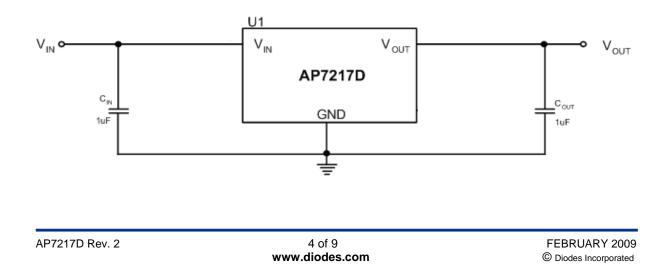
#### **Electrical Characteristics**

Symbol	Parameter	Test Conditions		Min	Тур.	Max	Unit
Ι <sub>Q</sub>	Quiescent Current	I <sub>O</sub> = 0mA		-	40	60	μA
V <sub>OUT</sub>	Output Voltage Accuracy	I <sub>O</sub> = 30mA		1.176	1.2	1.224	V
001	V <sub>OUT</sub> Temperature Coefficient	-40°C to 85°C, I <sub>OUT</sub> = 30mA		-	±100	-	ppm / °C
V <sub>DROPOUT</sub>	Dropout Voltage	I <sub>OUT</sub> = 600mA, V <sub>OUT</sub> = 1.2	2V	-	850	1300	mV
I <sub>OUT</sub>	Maximum Output Current			600	-	-	mA
I <sub>LIMIT</sub>	Current Limit			-	850	-	mA
ISHORT	Short Circuit Current			-	200	-	mA
$\Delta V_{LINE}$	Line Regulation	$2.5V \le V_{IN} \le 5.5V$ ; $I_{OUT} = 30mA$		-	0.2	-	%/V
	Load Regulation	$1mA \le I_{OUT} \le 300mA$			15	35	mV
$\Delta V_{LOAD}$	(Note 4)	1mA ≤ I <sub>OUT</sub> ≤ 600mA			30	55	mV
PSRR	Power Supply Rejection	V <sub>IN</sub> = 4.3V+0.5Vp-pAC, I <sub>OUT</sub> = 50mA	F = 1KHz	-	55	-	dB
	Thermal Shutdown Temperature			-	150	-	°C
	Thermal Shutdown Hysteresis			-	30	-	°C
θ <sub>JA</sub>	Thermal Resistance Junction-to-Ambient	SOT89-3L (Note 5)		-	173	-	°C/W
θ <sub>JC</sub>	Thermal Resistance Junction-to-Case	SOT89-3L (Note 5)		-	51	-	°C/W

 $(T_A = 25^{\circ}C, C_{IN} = 1\mu F, C_{OUT} = 1\mu F, V_{IN} = 5V$ , unless otherwise noted)

Notes: 4. Regulation is measured at constant junction temperature by low duty cycle pulse testing.
5. Test condition for SOT89-3L: Devices mounted on FR-4 substrate, single sided PC board, 2oz copper, with minimum recommended pad layout, no air flow.

# **Typical Application**

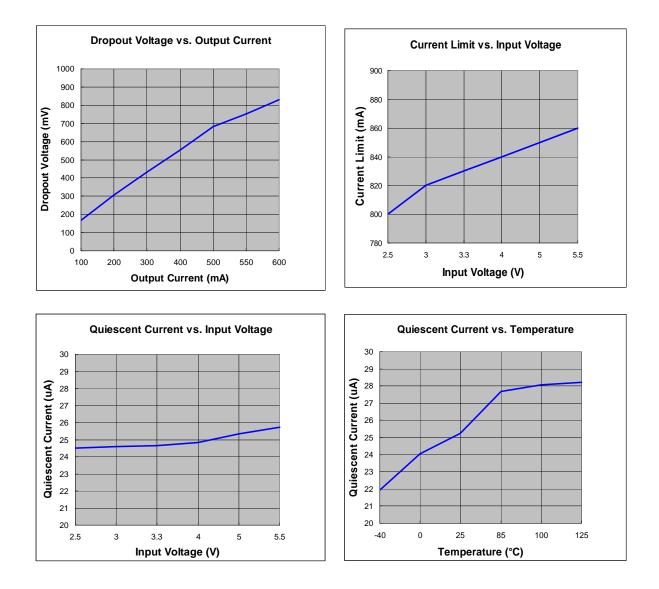




# AP7217D

### 1.2V 600mA CMOS LDO

# **Typical Performance Characteristics**

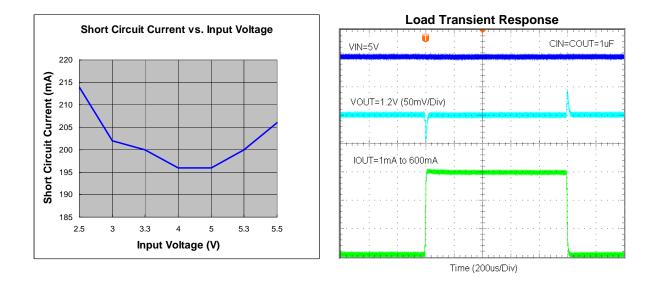




# AP7217D

## 1.2V 600mA CMOS LDO

# Typical Performance Characteristics (Continued)





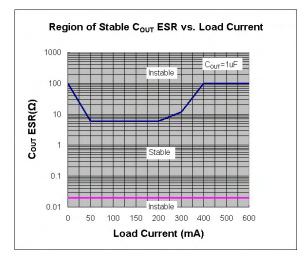
### **Application Information**

#### Input Capacitor

A 1 $\mu$ F ceramic capacitor is recommended to connect between IN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. A lower ESR (Equivalent Series Resistance) capacitor allows the use of less capacitance, while higher ESR type requires more capacitance. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both IN and GND.

#### **Output Capacitor**

The output capacitor is required to stabilize and help the transient response of the LDO. The AP7217D is designed to have excellent transient response for most applications with a small amount of output capacitance. The AP7217D is stable with any small ceramic output capacitors of  $1.0\mu$ F or higher value, and the temperature coefficients of X7R or X5R type. Additional capacitance helps to reduce undershoot and overshoot during transient. For PCB layout, the output capacitor must be placed as close as possible to OUT and GND pins, and keep the leads as short as possible.



#### **Thermal Considerations**

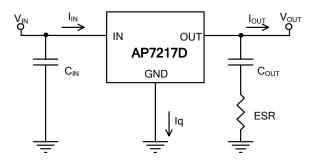
Thermal Shutdown Protection limits power dissipation in AP7217D. When the operation junction temperature exceeds 150°C, the Over Temperature Protection circuit starts the thermal shutdown function and turns the pass element off. The pass element turn on again after the junction temperature cools by 30°C. For continuous operation, do not exceed recommend maximum operation junction temperature 125°C. The power dissipation definition in device is:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{Q}$$

The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junctions to ambient. The maximum power dissipation can be calculated by following formula:

#### $P_{D(MAX)} = (T_{J(MAX)} - TA) / \theta_{JA}$

Where  $T_{J(MAX)}$  is the maximum operation junction temperature 125°C,  $T_A$  is the ambient temperature and the  $\theta_{JA}$  is the junction to ambient thermal resistance.



#### **Current Limit Protection**

When output current at OUT pin is higher than current limit threshold, the current limit protection will be triggered and clamp the output current to approximately 850mA to prevent over-current and to protect the regulator from damage due to overheating.

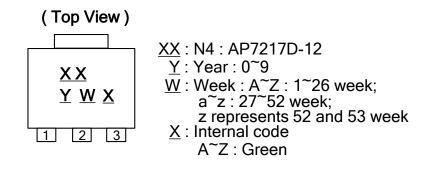
#### Short circuit protection

When  $V_{OUT}$  pin is shorted to GND or  $V_{OUT}$  voltage is less than 200mV, short circuit protection will be triggered and clamp the output current to approximately 200mA.



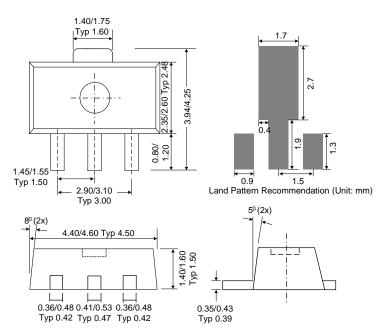
#### **Marking Information**

#### (1) SOT89-3L



#### Package Information (All Dimensions in mm)

#### (1) Package Type: SOT89-3L



AP7217D Rev. 2



#### IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

#### LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.